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Ultra Low Quiescent Current Linear Voltage Regulator

TLS810D1

TLS810D1EJV50 TLS810D1LDV50

Linear Voltage Regulator

Data Sheet

Rev. 1.1, 2015-11-02

Automotive Power



TLS810D1 TLS810D1EJ/LDV50





1 Overview

Features

- Ultra Low Quiescent Current of 9 μA
- Wide Input Voltage Range of 2.75 V to 42 V
- Output Current Capacity up to 100 mA
- Off Mode Current Less than 1 μA
- Low Drop Out Voltage of typ. 200 mV @ 100 mA
- Output Current Limit Protection
- Overtemperature Shutdown
- Enable
- Reset
- Available in PG-DSO-8 EP Package
- Available in PG-TSON-10 Package
- Wide Temperature Range
- Green Product (RoHS Compliant)
- AEC Qualified

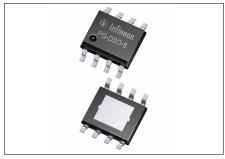


Figure 1 PG-DSO-8 EP

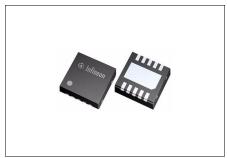


Figure 2 PG-TSON-10

Туре	Package	Marking
TLS810D1EJV50	PG-DSO-8 EP	810D1V50
TLS810D1LDV50	PG-TSON-10	810D1V50

TLS810D1EJ/LDV50



Overview

Description

The TLS810D1 is a linear voltage regulator featuring wide input voltage range, low drop out voltage and ultra low quiescent current.

With an input voltage range of 2.75 V to 42 V and ultra low quiescent of only 9 μ A, the regulator is perfectly suitable for automotive or any other supply systems connected permanently to the battery.

The TLS810D1EJ/LDV50 is the fixed 5 V output version with an accuracy of 2 % and output current capability up to 100 mA.

The new regulation concept implemented in TLS810D1 combines fast regulation and very good stability while requiring only a small ceramic capacitor of 1 μ F at the output.

The tracking region starts already at input voltages of 2.75 V (extended operating range). This makes the TLS810D1 also suitable to supply automotive systems that need to operate during cranking condition.

Internal protection features like output current limitation and overtemperature shutdown are implemented to protect the device against immediate damage due to failures like output short circuit to GND, over-current and over-temperature.

The device can be switched on and off by the Enable feature. When the device is switched off, the current consumption is typically less than 1 μ A.

The output voltage is supervised by the Reset feature, including undervoltage reset and delayed reset release at power-on.

Choosing External Components

An input capacitor $C_{\rm l}$ is recommended to compensate line influences. The output capacitor $C_{\rm Q}$ is necessary for the stability of the regulating circuit. Stability is guaranteed at values $C_{\rm Q} \ge 1~\mu{\rm F}$ and an ESR $\le 100~\Omega$ within the whole operating range.



Block Diagram

2 Block Diagram

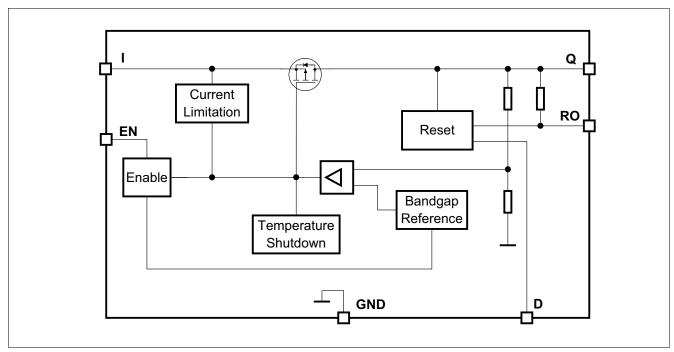


Figure 3 Block Diagram TLS810D1



Pin Configuration

3 Pin Configuration

3.1 Pin Assignment in PG-DSO-8 EP Package

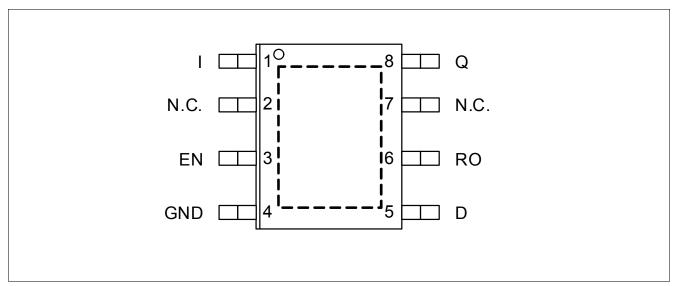


Figure 4 Pin Configuration TLS810D1 in PG-DSO-8 EP package

3.2 Pin Definitions and Functions in PG-DSO-8 EP Package

Pin	Symbol	Function
1	I	Input It is recommended to place a small ceramic capacitor (e.g. 100 nF) to GND, close to the IC terminals, in order to compensate line influences.
2	N.C.	Not connected
3	EN	Enable Integrated pull-down resistor. Enable the IC with high level input signal. Disable the IC with low level input signal.
4	GND	Ground
5	D	Reset Delay Timing Connect a ceramic capacitor to GND for adjusting the reset delay time. Leave open if the reset function is not needed.
6	RO	Reset Output Integrated pull-up resistor. Open collector output. Leave open if the reset function is not needed.
7	N.C.	Not connected



Pin Configuration

Pin	Symbol	Function
8	Q	Output
		Connect an output capacitor C_Q to GND close to the IC's terminals, respecting the values specified for its capacitance and ESR in Table 2 "Functional Range" on Page 9 .
Pad	_	Exposed Pad Connect to heatsink area. Connect to GND.

3.3 Pin Assignment in PG-TSON-10 Package

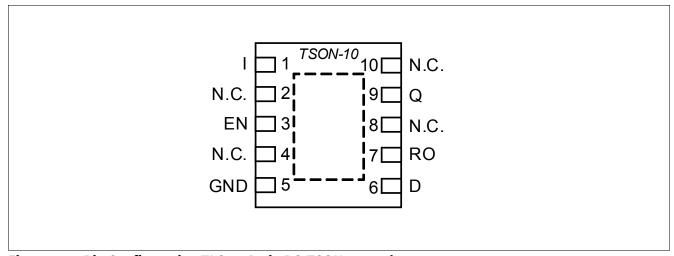


Figure 5 Pin Configuration TLS810D1 in PG-TSON-10 package

3.4 Pin Definitions and Functions in PG-TSON-10 Package

Pin	Symbol	Function
1	I	Input
		It is recommended to place a small ceramic capacitor (e.g. 100 nF) to GND, close to the IC terminals, in order to compensate line influences.
2	N.C.	Not connected
3	EN	Enable
		Integrated pull-down resistor.
		Enable the IC with high level input signal.
		Disable the IC with low level input signal.
4	N.C.	Not connected
5	GND	Ground

TLS810D1EJ/LDV50



Pin Configuration

Pin	Symbol	Function
6	D	Reset Delay Timing
		Connect a ceramic capacitor to GND for adjusting the reset delay time.
		Leave open if the reset function is not needed.
7	RO	Reset Output
		Integrated pull-up resistor.
		Open collector output.
		Leave open if the reset function is not needed.
8	N.C.	Not connected
9	Q	Output
		Connect an output capacitor $C_{\mathbb{Q}}$ to GND close to the IC's terminals, respecting the
		values specified for its capacitance and ESR in Table 2 "Functional Range" on
		Page 9.
10	N.C.	Not connected
Pad	_	Exposed Pad
		Connect to heatsink area.
		Connect to GND.



General Product Characteristics

4 General Product Characteristics

4.1 Absolute Maximum Ratings

Table 1 Absolute Maximum Ratings¹⁾

 T_i = -40 °C to +150 °C; all voltages with respect to ground (unless otherwise specified)

Parameter	Symbol		Value	S	Unit	Note or	Number
		Min.	Тур.	Max.		Test Condition	
Voltage Input I, Enable EN	<u>"</u>		-	,	ı	,	
Voltage	$V_{\rm I}, V_{\rm EN}$	-0.3	_	45	V	_	P_4.1.1
Voltage Output Q			·		·		
Voltage	$V_{\rm Q}$	-0.3	_	7	V	_	P_4.1.2
Reset Output RO, Reset De	lay D						
Voltage	$V_{\rm RO}, V_{\rm D}$	-0.3	_	7	V	_	P_4.1.3
Temperatures	<u>"</u>		-	,	ı	,	
Junction Temperature	T _j	-40	_	150	°C	_	P_4.1.4
Storage Temperature	$T_{\rm stg}$	-55	_	150	°C	-	P_4.1.5
ESD Absorption			-	,	ı	,	
ESD Susceptibility to GND	$V_{\rm ESD,HBM}$	-2	_	2	kV	HBM ²⁾	P_4.1.6
ESD Susceptibility to GND	V _{ESD,CDM}	-750	_	750	V	CDM ³⁾ at all pins	P_4.1.7

¹⁾ Not subject to production testing, specified by design.

Notes

- 1. Stresses above the ones listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.
- 2. Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation.

²⁾ ESD susceptibility, HBM according to ANSI/ESDA/JEDEC JS001 (1.5 k Ω , 100 pF)

³⁾ ESD susceptibility, Charged Device Model "CDM" according JEDEC JESD22-C101



General Product Characteristics

4.2 Functional Range

Table 2 Functional Range

Parameter	Symbol		Values		Unit	Note or Test Condition	Number
		Min.	Тур.	Max.			
Input Voltage Range	V _I	$V_{\rm Q,nom} + V_{\rm dr}$	_	42	٧	_1)	P_4.2.1
Extended Input Voltage Range	V _{I,ext}	2.75	_	42	٧	_2)	P_4.2.2
Output Capacitor	C_{Q}	1	_	_	μF	_3)4)	P_4.2.3
Output Capacitor's ESR	$ESR(C_Q)$	_	_	100	Ω	_4)	P_4.2.4
Junction temperature	T_{i}	-40	_	150	°C	_	P_4.2.5

- 1) Output current is limited internally and depends on the input voltage, see Electrical Characteristics for more details.
- 2) When V_1 is between $V_{l,\text{ext.min}}$ and $V_{Q,\text{nom}} + V_{dr}$, $V_Q = V_1 V_{dr}$. When V_1 is below $V_{l,\text{ext,min}}$, V_Q can drop down to 0 V.
- 3) The minimum output capacitance requirement is applicable for a worst case capacitance tolerance of 30%.
- 4) Not subject to production testing, specified by design.

Note: Within the functional or operating range, the IC operates as described in the circuit description. The electrical characteristics are specified within the conditions given in the Electrical Characteristics table.



General Product Characteristics

4.3 Thermal Resistance

Note: This thermal data was generated in accordance with JEDEC JESD51 standards. For more information, go to www.jedec.org.

Table 3 Thermal Resistance TLS810D1 in PG-DSO-8 EP Package

					•		
Parameter	Symbol	Values			Unit	Note or	Number
		Min.	Тур.	Max.		Test Condition	
Package Version		1		<u> </u>		1	
Junction to Case ¹⁾	R_{thJC}	-	19	_	K/W	_	P_4.3.1
Junction to Ambient	R_{thJA}	_	51	_	K/W	2s2p board ²⁾	P_4.3.2
Junction to Ambient	R_{thJA}	-	167	-	K/W	1s0p board, footprint only ³⁾	P_4.3.3
Junction to Ambient	R_{thJA}	-	71	-	K/W	1s0p board, 300 mm ² heatsink area on PCB ³⁾	P_4.3.4
Junction to Ambient	R_{thJA}	-	60	-	K/W	1s0p board, 600 mm ² heatsink area on PCB ³⁾	P_4.3.5

¹⁾ Not subject to production test, specified by design

Table 4 Thermal Resistance TLS810D1 in PG-TSON-10 Package

Parameter	Symbol	ol Values			Unit	Note or	Number
		Min.	Тур.	Max.		Test Condition	
Package Version	<u> </u>		"				•
Junction to Case ¹⁾	R_{thJC}	-	13	_	K/W	_	P_4.3.6
Junction to Ambient	R_{thJA}	-	60	_	K/W	2s2p board ²⁾	P_4.3.7
Junction to Ambient	R_{thJA}	-	184	_	K/W	1s0p board, footprint only ³⁾	P_4.3.8
Junction to Ambient	R_{thJA}	-	75	-	K/W	1s0p board, 300 mm ² heatsink area on PCB ³⁾	P_4.3.9
Junction to Ambient	R_{thJA}	-	64	-	K/W	1s0p board, 600 mm ² heatsink area on PCB ³⁾	P_4.3.10

¹⁾ Not subject to production test, specified by design

²⁾ Specified R_{thJA} value is according to Jedec JESD51-2,-5,-7 at natural convection on FR4 2s2p board; The Product (Chip+Package) was simulated on a 76.2 x 114.3 x 1.5 mm³ board with 2 inner copper layers (2 x 70 μ m Cu, 2 x 35 μ m Cu). Where applicable a thermal via array under the exposed pad contacted the first inner copper layer.

³⁾ Specified R_{thJA} value is according to JEDEC JESD 51-3 at natural convection on FR4 1s0p board; The Product (Chip+Package) was simulated on a 76.2 × 114.3 × 1.5 mm³ board with 1 copper layer (1 x 70µm Cu).

²⁾ Specified R_{thJA} value is according to Jedec JESD51-2,-5,-7 at natural convection on FR4 2s2p board; The Product (Chip+Package) was simulated on a 76.2 x 114.3 x 1.5 mm³ board with 2 inner copper layers (2 x 70 μ m Cu, 2 x 35 μ m Cu). Where applicable a thermal via array under the exposed pad contacted the first inner copper layer.

³⁾ Specified R_{thJA} value is according to JEDEC JESD 51-3 at natural convection on FR4 1s0p board; The Product (Chip+Package) was simulated on a 76.2 × 114.3 × 1.5 mm³ board with 1 copper layer (1 x 70 μ m Cu).



5 Block Description and Electrical Characteristics

5.1 Voltage Regulation

The output voltage V_Q is divided by a resistor network. This fractional voltage is compared to an internal voltage reference and the pass transistor is driven accordingly.

The control loop stability depends on the output capacitor C_Q , the load current, the chip temperature and the internal circuit structure. To ensure stable operation, the output capacitor's capacitance and its equivalent series resistor ESR requirements given in "Functional Range" on Page 9 have to be maintained. For details see the typical performance graph Output Capacitor Series Resistor ESR(C_Q) versus Output Current C_Q . Since the output capacitor is used to buffer load steps, it should be sized according to the application's needs.

An input capacitor C_1 is not required for stability, but is recommended to compensate line fluctuations. An additional reverse polarity protection diode and a combination of several capacitors for filtering should be used, in case the input is connected directly to the battery line. Connect the capacitors close to the regulator terminals.

In order to prevent overshoots during start-up, a smooth ramping up function is implemented. This ensures almost no overshoots during start-up, mostly independent from load and output capacitance.

Whenever the load current exceeds the specified limit, e.g. in case of a short circuit, the output current is limited and the output voltage decreases.

The overtemperature shutdown circuit prevents the IC from immediate destruction under fault conditions (e.g. output continuously short-circuit) by switching off the power stage. After the chip has cooled down, the regulator restarts. This oscillatory thermal behaviour causes the junction temperature to exceed the maximum rating of 150°C and can significantly reduce the IC's lifetime.

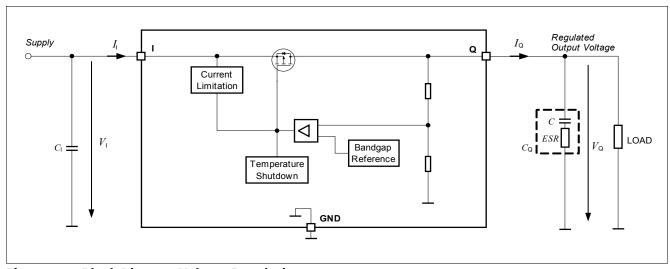


Figure 6 Block Diagram Voltage Regulation



Table 5 Electrical Characteristics

 $T_{\rm j}$ = -40 °C to +150 °C, $V_{\rm l}$ = 13.5 V, all voltages with respect to ground (unless otherwise specified). Typical values are given at $T_{\rm i}$ = 25 °C, $V_{\rm l}$ = 13.5 V.

Parameter	Symbol	Values			Unit	Note or Test Condition	Number
		Min.	Тур.	Max.			
Output Voltage Precision	V_{Q}	4.90	5.00	5.10	V	50 μA $\leq I_Q \leq$ 100 mA, 5.7 V $\leq V_1 \leq$ 28 V	P_5.1.1
Output Voltage Precision	V_{Q}	4.90	5.00	5.10	V	$50 \mu A ≤ I_Q ≤ 50 mA$, $5.7 V ≤ V_I ≤ 42 V$	P_5.1.2
Output Current Limitation	$I_{Q,lim}$	110	190	260	mA	$0 \text{ V} \le V_{\text{Q}} \le V_{\text{Q,nom}} - 0.1 \text{ V}$	P_5.1.3
Line Regulation steady-state	$\Delta V_{ m Q,line}$	-	1	20	mV	$I_Q = 1 \text{ mA}, 6 \text{ V} \le V_1 \le 32 \text{ V}$	P_5.1.4
Load Regulation steady-state	$\Delta V_{ m Q,load}$	-20	-1	-	mV	$V_1 = 6 \text{ V},$ 50 $\mu \text{A} \le I_0 \le 100 \text{ mA}$	P_5.1.5
Dropout Voltage ¹⁾ $V_{dr} = V_I - V_Q$	$V_{\rm dr}$	-	200	550	mV	$I_{\rm Q} = 100 {\rm mA}$	P_5.1.6
Ripple Rejection ²⁾	PSRR	-	55	-	dB	$I_{\rm Q}$ = 50 mA, $f_{\rm ripple}$ = 100 Hz, $V_{\rm ripple}$ = 0.5 $V_{\rm p-p}$	P_5.1.7
Overtemperature Shutdown Threshold	$T_{\rm j,sd}$	151	175	-	°C	T _j increasing	P_5.1.8
Overtemperature Shutdown Threshold Hysteresis	T _{j,sdh}	-	10	-	K	T _j decreasing	P_5.1.9

¹⁾ Measured when the output voltage V_Q has dropped 100 mV from the nominal value obtained at $V_I = 13.5$ V

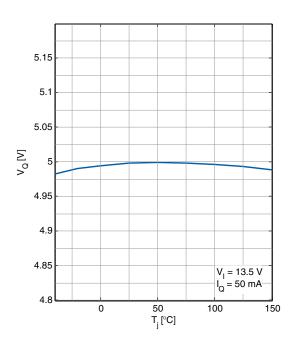
²⁾ Not subject to production test, specified by design



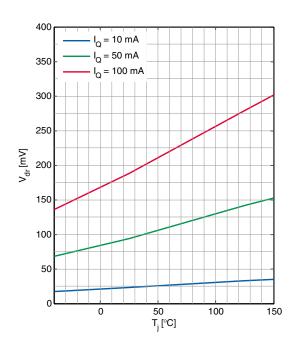
5.2 Typical Performance Characteristics Voltage Regulation

Typical Performance Characteristics

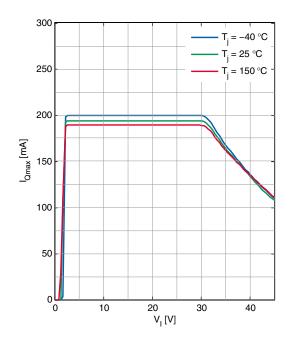
Output Voltage $V_{\mathbf{Q}}$ versus Junction Temperature $T_{\mathbf{i}}$



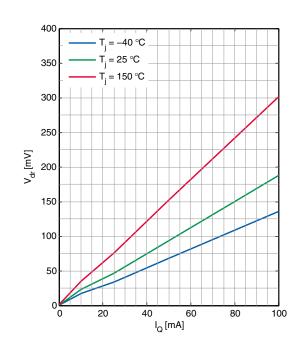
Dropout Voltage $V_{\rm dr}$ versus Junction Temperature $T_{\rm i}$



Output Current I_Q versus Input Voltage V_I

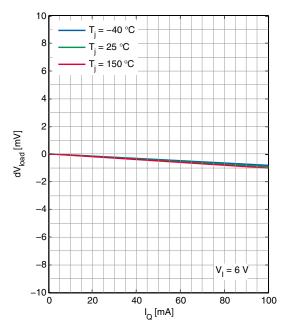


Dropout Voltage $V_{\rm dr}$ versus Output Current $I_{\rm O}$

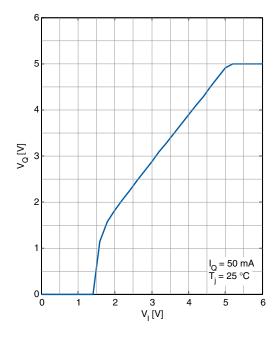




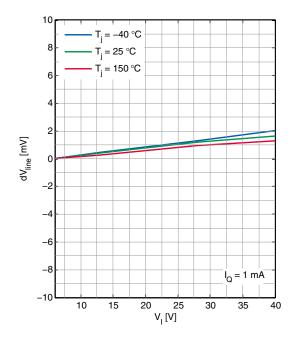
Load Regulation $\Delta V_{\rm Q,load}$ versus Output Current $I_{\rm O}$



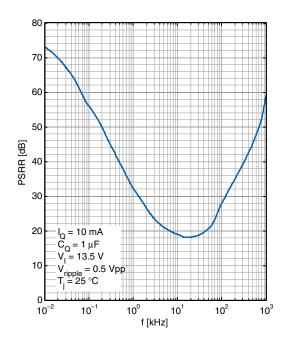
Output Voltage $V_{\mathbf{Q}}$ versus Input Voltage $V_{\mathbf{I}}$



Line Regulation $\Delta V_{\rm Q,line}$ versus Input Voltage $V_{\rm I}$

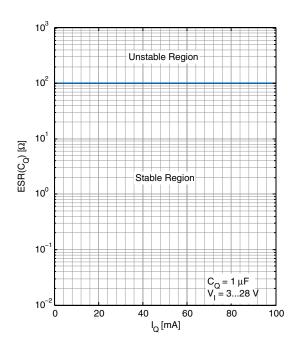


Power Supply Ripple Rejection PSRR versus Ripple Frequency $f_{\mathbf{r}}$





Output Capacitor Series Resistor $ESR(C_Q)$ versus Output Current I_Q





5.3 Current Consumption

Table 6 Electrical Characteristics Current Consumption

 $T_{\rm i}$ = -40 °C to +150 °C, $V_{\rm i}$ = 13.5 V (unless otherwise specified).

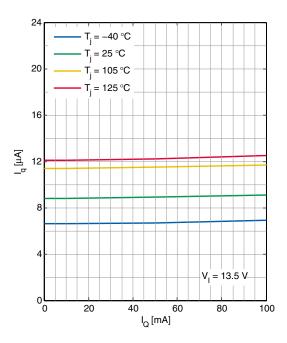
Parameter	Symbol	Values		Unit	Note or Test Condition	Number	
		Min.	Тур.	Max.			
Current Consumption $I_q = I_1$	$I_{\mathrm{q,off}}$	-	-	1	μΑ	$V_{\rm EN} \le 0.4 \rm V, T_{\rm j} < 105 ^{\circ} \rm C$	P_5.3.1
Current Consumption $I_q = I_1 - I_Q$	Iq	_	9	11.5	μΑ	$I_{Q} = 50 \mu A, T_{j} = 25 \text{ °C}$	P_5.3.2
Current Consumption $I_q = I_1 - I_Q$	Iq	_	11.5	14.5	μΑ	$I_{Q} = 50 \mu A, T_{j} < 105 ^{\circ} C$	P_5.3.3
Current Consumption $I_q = I_1 - I_Q$	Iq	-	12	16	μΑ	$I_{\rm Q} = 50 \; \mu \text{A}, T_{\rm j} < 125 ^{\circ} \text{C}$	P_5.3.4
Current Consumption $I_q = I_1 - I_Q$	Iq	-	12	16	μΑ	$I_{\rm Q}$ = 100 mA, $T_{\rm j}$ < 125 °C	P_5.3.5



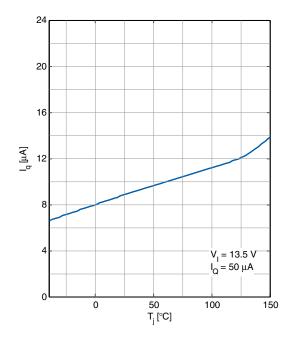
5.4 Typical Performance Characteristics Current Consumption

Typical Performance Characteristics

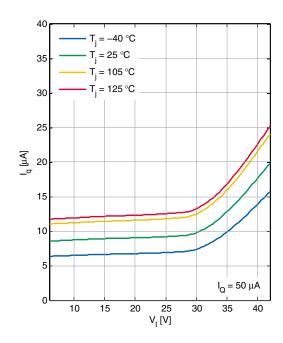
Current Consumption $I_{\bf q}$ versus Output Current $I_{\bf O}$



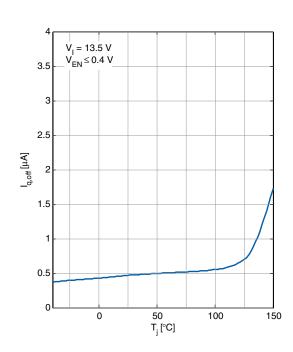
Current Consumption $I_{\bf q}$ versus Junction Temperature $T_{\bf i}$



Current Consumption I_q versus Input Voltage V_I



Current Consumption in OFF mode $I_{\mathbf{q}, \mathrm{off}}$ versus Junction Temperature $T_{\mathbf{i}}$





5.5 Enable

The device can be switched on and off by the Enable feature. Connect a HIGH level as specified below (e.g. the battery voltage) to pin EN to enable the device; connect a LOW level as specified below (e.g. GND) to switch it off. The Enable function has a build-in hysteresis to avoid toggling between ON/OFF state, if signals with slow slopes are appiled to the EN input.

Table 7 Electrical Characteristics Enable

 $T_{\rm j}$ = -40 °C to +150 °C, $V_{\rm l}$ = 13.5 V, all voltages with respect to ground (unless otherwise specified). Typical values are given at $T_{\rm i}$ = 25 °C, $V_{\rm l}$ = 13.5 V.

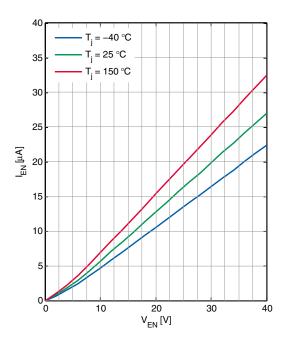
Parameter	Symbol	Values			Unit	Note or Test Condition	Number
		Min.	Тур.	Max.			
Enable High Level Input Voltage	$V_{\rm EN,H}$	2	-	-	V	V _Q settled	P_5.5.1
Enable Low Level Input Voltage	$V_{\rm EN,L}$	-	-	0.8	V	$V_{\rm Q} \le 0.1 \rm V$	P_5.5.2
Enable High Level Input Current	I _{EN,H}	-	-	4	μΑ	V _{EN} = 5 V	P_5.5.3
Enable Internal Pull-down Resistor	R _{EN}	1.25	2	3.5	МΩ	-	P_5.5.4



5.6 Typical Performance Characteristics Enable

Typical Performance Characteristics

Enable Input Current $I_{\rm EN}$ versus Enable Input Voltage $V_{\rm EN}$





5.7 Reset Function

The reset function provides several features:

Output Undervoltage Reset

An output undervoltage condition is indicated by setting the Reset Output RO to "low". This signal may be used to reset a microcontroller during low supply voltage.

Power-On Reset Delay Time

The power-on reset delay time $t_{\rm rd}$ allows microcontoller and oscillator to start up. This delay time is the time frame from exceeding the reset switching threshold $V_{\rm RT}$ until the reset is released by switching the reset output "RO" from "low" to "high". The power-on reset delay time trd is defined by an external delay capacitor $C_{\rm D}$ connected to pin D charged by the delay capacitor charge current $I_{\rm D,ch}$ starting from $V_{\rm D}$ = 0 V.

If the application needs a power-on reset delay time $t_{\rm rd}$ different from the value given in **Table 8**, the delay capacitor's value can be derived from the specified value and the desired power-on delay time:

$$C_{\rm D} = \frac{t_{\rm rd,new}}{t_{\rm rd}} \bullet 100 \,\text{nF} \tag{5.1}$$

with

- C_D : capacitance of the delay capacitor to be chosen
- $t_{\text{rd,new}}$: desired power-on reset delay time
- t_{rd}: power-on reset delay time specified in this datasheet

For a precise calculation also take the delay capacitor's tolerance into consideration.

Reset Reaction Time

The reset reaction rime $t_{\rm rr}$ considers the internal reaction time $t_{\rm rr,int}$ and the discharge time $t_{\rm rr,d}$ defined by the external delay capacitor $C_{\rm D}$ (see typical performance graph for details). Hence, the total reset reaction time becomes:

$$t_{\rm rr} = t_{\rm rr,int} + t_{\rm rr,d} \tag{5.2}$$

with

- t_{rr}: reset reaction time
- $t_{\text{rr.int}}$: internal reset reaction time
- t_{rr.d}: reset discharge

Optional Reset Output Pull-Up Resistor $R_{RO,ext}$

The Reset Output RO is an open collector output with an integrated pull-up resistor. If needed, an external pull-up resistor to the output Q can be added. In **Table 8** a minimum value for the external resistor $R_{RO,ext}$ is given.



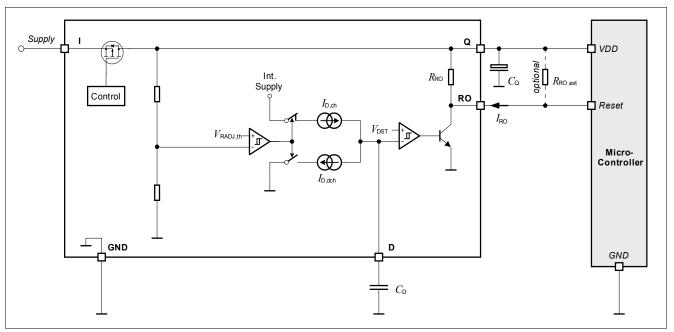


Figure 7 Block Diagram Reset Function



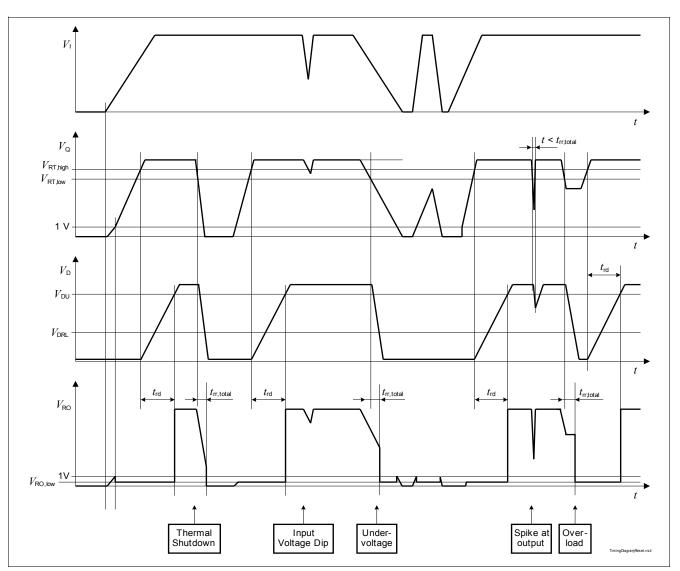


Figure 8 Timing Diagram Reset

Table 8 Electrical Characteristics Reset

 $T_{\rm j}$ = -40 °C to +150 °C, $V_{\rm j}$ = 13.5 V, all voltages with respect to ground (unless otherwise specified). Typical values are given at $T_{\rm j}$ = 25 °C, $V_{\rm j}$ = 13.5 V.

Parameter	Symbol	Values			Unit	Note or	Number
		Min.	Тур.	Max.		Test Condition	
Output Undervoltage Reset			•		•		
Output Undervoltage Reset Upper Switching Threshold	$V_{RT,high}$	4.6	4.7	4.8	V	V _Q increasing, V _{EN} ≥ 2.0 V	P_5.7.1
Output Undervoltage Reset Lower Switching Threshold	$V_{ m RT,low}$	4.5	4.6	4.7	V	V _Q decreasing, V _{EN} ≥ 2.0 V	P_5.7.2

Reset Output RO



Table 8 Electrical Characteristics Reset (cont'd)

 $T_{\rm j}$ = -40 °C to +150 °C, $V_{\rm l}$ = 13.5 V, all voltages with respect to ground (unless otherwise specified). Typical values are given at $T_{\rm j}$ = 25 °C, $V_{\rm l}$ = 13.5 V.

Parameter	Symbol	Values			Unit	Note or	Number
		Min.	Тур.	Max.		Test Condition	
Reset Output Low Voltage	V _{RO,low}	0	0.2	0.4	V	$1 \text{ V} \le V_{\text{Q}} \le V_{\text{RT}};$ $R_{\text{RO}} > 4.7 \text{ k}\Omega$	P_5.7.3
Reset Output Internal Pull-Up Resistor	R _{RO,int}	13	20	36	kΩ	Internally connected to Q	P_5.7.4
Reset Output External Pull-up Resistor to V _Q	R _{RO,ext}	4.7	-	-	kΩ	$1 \text{ V} \le V_{\text{Q}} \le V_{\text{RT}};$ $V_{\text{RO}} \le 0.4 \text{ V}$	P_5.7.5
Reset Delay Timing							
Power On Reset Delay Time	t _{rd}	17	25	37	ms	C _D = 100 nF Calculated vaule	P_5.7.6
Upper Delay Switching Threshold	V _{DU}	_	0.9	-	V	-	P_5.7.7
Lower Delay Switching Threshold	V_{DL}	-	0.6	-	V	-	P_5.7.8
Delay Capacitor Charge Current	$I_{\rm D,ch}$	_	3.6	-	μΑ	V _D = 1 V	P_5.7.9
Delay Capacitor Discharge Current	I _{D,dch}	-	250	-	mA	V _D = 1 V	P_5.7.10
Delay Capacitor Discharge Time	t _{rr,d}	-	2	4	μs	C _D = 100 nF Calculated value	P_5.7.11
Internal Reset Reaction Time ¹⁾	$t_{\rm rr,int}$	_	8	14	μs	$C_D = 0 \text{ nF}$	P_5.7.12
Reset Reaction Time	$t_{\rm rr,total}$	-	10	18	μs	C _D = 100 nF Calculated value	P_5.7.13

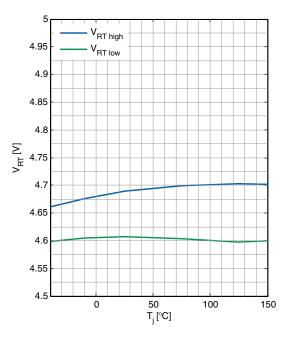
¹⁾ Parameter not subject to production test; specified by design.



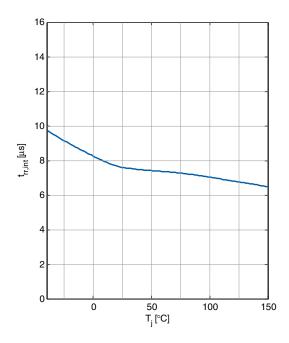
5.8 Typical Performance Characteristics Reset

Typical Performance Characteristics

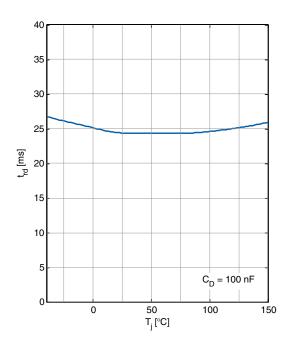
Undervoltage Reset Threshold V_{RT} versus Junction Temperature T_{i}



Internal Reset Reaction Time $t_{\rm rr,int}$ versus Junction Temperature $T_{\rm j}$



Power On Reset Delay Time $t_{\rm rd}$ versus Junction Temperature $T_{\rm j}$





Application Information

6 Application Information

Note: The following information is given as a hint for the implementation of the device only and shall not be regarded as a description or warranty of a certain functionality, condition or quality of the device.

6.1 Application Diagram

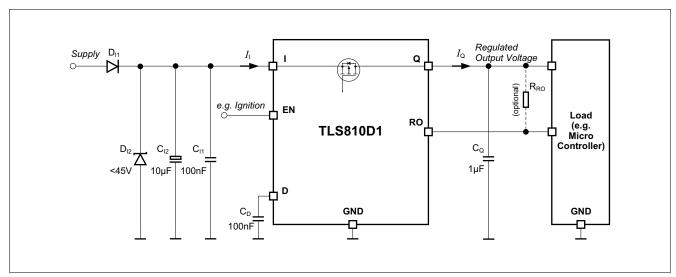


Figure 9 Application Diagram

6.2 Selection of External Components

6.2.1 Input Pin

The typical input circuitry for a linear voltage regulator is shown in the application diagram above.

A ceramic capacitor at the input, in the range of 100 nF to 470 nF, is recommended to filter out the high frequency disturbances imposed by the line e.g. ISO pulses 3a/b. This capacitor must be placed very close to the input pin of the linear voltage regulator on the PCB.

An aluminum electrolytic capacitor in the range of $10\,\mu\text{F}$ to $470\,\mu\text{F}$ is recommended as an input buffer to smooth out high energy pulses, such as ISO pulse 2a. This capacitor should be placed close to the input pin of the linear voltage regulator on the PCB.

An overvoltage suppressor diode can be used to further suppress any high voltage beyond the maximum rating of the linear voltage regulator and protect the device against any damage due to over-voltage.

The external components at the input are not mandatory for the operation of the voltage regulator, but they are recommended in case of possible external disturbances.